STM/AFM investigations of $\beta$-MoTe$_2$, $\alpha$-MoTe$_2$ and WTe$_2$

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Abstract

There is controversy in the literature concerning the correspondence of STM images to the atomic positions on some transition metal layered dichalcogenide surfaces. Although it is difficult to differentiate between metal and chalcogen atoms in these crystals with hexagonal symmetry, like $\alpha$-MoTe$_2$, this can be done in cases of $\beta$-MoTe$_2$ and WTe$_2$ with changed metal–Te distances. Contrary to published STM images of WTe$_2$ our STM images of $\beta$-MoTe$_2$ show details which resemble the structure of both corrugated topmost Te and metal layers. The d$_{z^2}$ orbitals of metal atoms protruding vertically upward may provide the tunneling current in this case. The detection of surface or sub-surface atoms depends on the tip electronic condition. The STM results are compared with those from AFM.

Keywords: Atomic force microscopy; Molybdenum ditelluride; Scanning tunneling microscopy; Tungsten ditelluride

1. Introduction

TMD (transition metal dichalcogenide) crystals are widely studied by SPM due to their various potential applications. In general, they are composed of two-dimensional hexagonally packed chalcogen–metal–chalcogen sandwiches with strong covalent bonds inside and weak van der Waals interactions between the sandwiches. Cleavage faces of TMD crystals usually give chalcogen terminated (001) surfaces. Their structures do not differ from terminated bulk structures in many TMD compounds since they are free of dangling bonds and hence do not reconstruct.

In several reports, it is argued that the STM images of TMD surfaces represent metal layers rather than chalcogen ones [1–3]. The dominant part of the wave functions in both valence band top and conduction band bottom of these materials consist of free metal d$_{z^2}$ orbitals which may provide the tunneling current while the chalcogen atomic orbitals are exclusively involved in intralayer bonding. Since both metal and chalcogen layers in most TMD crystals have the same symmetry and in-plane lattice constants (Fig. 1a) and since STM in its topographical mode cannot distinguish between chemical species, it is difficult to decide which atoms are mainly contributing to the STM images.

To clarify this problem, several studies have been carried out on WTe$_2$ [3–5], in which the structures of Te and W layers are different (Fig. 1b) [6,7]. However, the STM images of WTe$_2$ surfaces show
both Te- and W-layer-like structures which calls for further investigations. The first principles pseudopotential calculation result on WTe₂ shows [4] that the charge distribution of the topmost Te atoms is shifted toward the metal atoms causing a W-layer-like image. Therefore, Te-layer-like and W-layer-like structures in STM images of WTe₂ cannot be definitely ascribed to Te or W atoms. However, according to the same calculation [4], the charge displacement occurs only at the negative sample bias. For the positive sample bias, the charge distributions are almost centered at the actual atomic positions. This is in disagreement with the experiments where the same kind of images [4] are obtained with both sample biases.

To get a better understanding of the STM images of TMD surfaces we investigated α-MoTe₂, β-MoTe₂, and WTe₂(001) surfaces by AFM and STM. α- and β-MoTe₂ have been chosen because of their chemically identical but structurally different nature [6,7]. In addition, experiments on WTe₂ were included to be compared with published results and due to the structural similarities of the (001) surfaces of WTe₂ and β-MoTe₂.

2. Experimental

All crystals were grown by chemical vapor transport in evacuated silica tubes with I₂ as the transport agent. Their structures were confirmed by XRD measurements. The samples were cleaved with an adhesive tape just before the experiments. STM investigations were performed using an Omicron UHV STM system with an operating pressure between 10⁻¹⁰ and 10⁻¹¹ mbar. The STM was operated in the constant current mode. Electrochemically etched tungsten tips were used throughout this work. The quality of each tip was pre-examined by scanning a test image on graphite prior to each experiment.

AFM examinations were performed with a Digital Instruments Nanoscope III SPM system in air in the contact and lateral force modes and silicon nitride cantilevers were used. Mica was used for adjustment of the AFM scanner and to check the quality of the cantilever.

3. Results and discussion

3.1. α-MoTe₂

Atomic resolution STM images of α-MoTe₂ were obtained with both positive and negative polarities of
the sample varying from $+0.5$ to $+2.5$ V and from $-0.3$ to $-3$ V, respectively. The tunneling currents were within the range from 0.5 to 4 nA. There was virtually no atomic resolution obtained from $-0.3$ to 0.5 V which approximately corresponds to the band gap of this material [6]. Fig. 2a and Fig. 2b show STM and AFM images of $\alpha$-MoTe$_2$ surface. Contrary to the AFM image of the $\alpha$-MoTe$_2$, the STM image contains both metal and chalcogen charge density contributions. Several published STM images of TMD surfaces, such as MoS$_2$ and NbSe$_2$ [8], also show both chalcogen and metal contributions. Though, one cannot distinguish between chalcogen and metal charge densities in these images, they certainly prove that the metal d$_{z^2}$ orbitals can penetrate outward and can provide tunneling current.

3.2. $\beta$-MoTe$_2$

The STM images of (001) $\beta$-MoTe$_2$ surfaces were taken with tip-to-sample bias voltage ranging from $-0.3$ mV to $-1$ V and $+0.3$ mV to $+1$ V. The tunneling current range was between 0.03 and 45 nA.

The reduction of Mo–Mo bond lengths in $\beta$-MoTe$_2$ as compared with that of $\alpha$-MoTe$_2$ causes indirect band overlapping which results in a semi-metallic behavior [6]. This is reflected in STM imaging, where good atomic resolution can be obtained even with very low bias voltage ($\pm 0.3$ mV) which is not the case for semiconducting $\alpha$-MoTe$_2$. The best atomic resolutions are obtained with bias voltages from $+0.3$ mV to $+0.5$ V and $-0.3$ mV to $-1$ V.

The STM images of $\beta$-MoTe$_2$ resemble either the atomic configuration of the topmost Te layer (Fig. 3a) or the subsurface Mo layer (Fig. 3b) or combinations of both. All three kinds of images were observed for both positive and negative sample voltages while the AFM image (Fig. 3c) shows the expected chalcogen surface topography. Different images appear more often at reduced bias voltages (close to the Fermi level) especially within $+0.3$ mV to $3$ V and $-0.3$ mV to $-3$ V regions. Since the density of states (DOS) for $\beta$-MoTe$_2$ contains both metal ‘d’ and chalcogen ‘p’ energy levels close to the Fermi level [6], it is possible that both atoms contribute to the tunneling current at suitable circumstances.

To determine the influence of the tip-to-sample distance in this case, STM images were recorded by varying the tunneling current between 0.03 and 45 nA at each bias voltage. It was found that with the tip far away from the surface ($I$, below 0.5 nA), only Te-layer-like images were observed at both bias voltage polarities. With the tip closer to the surface ($I$, between 0.5 and 3.5 nA), both Mo-layer-like and Te-layer-like images were observed with approximately equal frequency.
This can be explained as follows: with the tip far away from the surface, the subsurface metal $d_z$ orbitals are at a larger distance from the tip than the surface chalcogen "p" orbitals and hence they do not overlap with the tip wavefunctions. Since only the wavefunctions from the chalcogen "p" orbitals overlap with the tip wavefunctions at this stage, all the images are Te-layer-like. When the tip is close enough to the surface, the free metal $d_z$ orbitals can also contribute to the tunneling current.

In Fig. 4, showing the STM image of $\beta$-MoTe$_2$ taken at $U_g = 0.7$ mV and $I_t = 1.2$ nA, both Te and metal layers are visible. In this image, average measured distances between the bright spots are close to the metal–metal distances while the distances between the fainter ones are close to the chalcogen–
chalalogen distances \( (m_1 = 3.96 \text{ Å}, m_2 = 2.24 \text{ Å},
\text{ and } e_2 = 3.06 \text{ Å and } e_3 = 3.18 \text{ Å as compared with Fig. 1). This image proves that the contribution of the metal charge density to the tunneling current can be higher than that of the chalcogens under certain conditions. Fig. 5 demonstrates the change from Te-layer-like image to metal-layer-like image after a scan artefact.}

\[3.3. \text{WTe}_2\]

The STM images of WTe\(_2\) were obtained at almost the same tunneling parameters as those of \(\beta\)-MoTe\(_2\). Fig. 6a and Fig. 6b show the Te- and W-layer-like images of the WTe\(_2\) (001) surface and Fig. 6c is the corresponding AFM image. As in case of \(\beta\)-MoTe\(_2\), only Te-layer-like images are observed with the tip far from the surface and both types of images can be observed for close enough tips. These observations are independent of specimen bias voltage polarities in contrast with the calculated result [4], according to which W-layer-like images can be observed only at negative sample biases.

\[4. \text{Conclusions}\]

1. The AFM images of \(\alpha\)-MoTe\(_2\), \(\beta\)-MoTe\(_2\) and WTe\(_2\) show expected chalcogen surface topographies while the corresponding STM images contain chalcogen or metal or both chalcogen and metal contributions. This is due to the free metal \(d_{z^2}\) orbitals which provide tunneling current at certain conditions.

2. In cases of \(\beta\)-MoTe\(_2\) and WTe\(_2\), the observation of the metal- and chalcogen-like structures does not depend on the sample biases since both can be observed at positive as well as negative biases.
3. Present experiments show that chalcogen as well as metal atoms can contribute to the STM images of TMD surfaces depending on the tip-to-sample distance.

4. In addition, the two types of images can switch from one into the other during a single scan. Imaging of metal or chalcogen atoms depends on the tip conditions. The tip structure and corresponding electronic states may change during scanning and create conditions for imaging either metal or chalcogen atoms.

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References